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SAM™ Data Sheet SAM-1030-32-2ps-x, λ = 1030 nm

Laser wavelength $\lambda = 1030 \text{ nm}$ High reflection band $\lambda = 960 \dots 1050 \text{ nm}$		
High reflection band $\lambda = 960 \dots 1050 \text{ nm}$		
Absorbance $A_0 = 32 \%$		
Modulation depth $\Delta R = 20 \%$		
Non-saturable loss $A_{ns} = 12 \%$		
Saturation fluence $\Phi_{sat} = 70 \ \mu J/cm^2$		
Relaxation time constant $\tau = 2 \text{ ps}$		
Damage threshold $\Phi = 800 \ \mu J/cm^2$		
Chip area 4.0 mm x 4.0 mm; other dimensions on request		
Chip thickness 450 µm		
Protection the SAM is protected with a dielectric front layer		
Mounting option x denotes the type of mounting as follows: x = 0 unmounted x = 12.7 g glued on a gold plated Cu civilinder with 12.7 mm $%$		

x = 12.7 g	glued on a gold plated Cu-cylinder with 12.7 mm $arnothing$
x = 25.4 g	glued on a gold plated Cu-cylinder with 25.4 mm $arnothing$
x = 12.7 s	soldered on a gold plated Cu-cylinder with 12.7 mm $arnothing$
x = 25.4 s	soldered on a gold plated Cu-cylinder with 25.4 mm $arnothing$
x = FC	mounted on a 1 m monomode fiber cable with FC connector

Low intensity spectral reflectance

